

Name : Kuan-Chen Chen

Education :

- Feng Chia University, Taiwan
Doctor of Philosophy in Materials Science and Engineering

Career Experience :

- Central Taiwan University of Science and Technology, Taiwan
Assistant Professor, Department of Dental Technology and Materials Science

Courses Taught :

- Removable Partial Denture Technology
- Dental Morphology
- Dental Materials Science

Professional Fields :

- Removable Prosthodontics
- Dental Technology
- Dental Materials

Research Interests :

- Materials Science
- VHF Plasma

Representative Publication in 5 Years :

Journal Articles :

1.

K.-C. Chen, K.-F. Chiu, C.-F. Chen, C.-Y. Lien, Y.-J. Tsai, T.-K. Lien, F. Matsunaga, M. Tanaka, K. Ogiwara, K. Uchino, and Y. Kawai, “Observation of bi-Maxwellian distributions in a H₂ plasma produced by a narrow gap VHF discharge”, *Plasma Process. Polym.* vol. 13, 6, pp. 584-587, June, 2016. (SCI,EI)

2.

K.-C. Chen, C.-F. Chen, C.-Y. Lien, K.-F. Chiu, J.-B. Shi, Y.-J. Tsai, T.-K. Lien, K. Ogiwara, K. Uchino, and Y. Kawai, “Axial distribution of a VHF H₂ plasma produced by a narrow gap discharge”, *Jpn. J. Appl. Phys.* vol. 55, pp. 01AH01-1-01AH01-5, January, 2016. (SCI,EI)

3.

K.-C. Chen, K. Ogiwara, K.-F. Chiu, L.-W. Su, K. Uchino, and Y. Kawai, “Two-dimensional simulations of a VHF H₂ plasma for different discharge gaps and gas pressures”, *Jpn. J. Appl. Phys.* vol. 55, pp. 07LD01-1-07LD01-6, July, 2016. (SCI,EI)

4.

K.-C. Chen, K.-F. Chiu, C.-F. Chen, C.-Y. Lien, Y.-J. Tsai, T.-K. Lien, K. Ogiwara, K. Uchino, and Y. Kawai, “Mechanism of VHF H₂ plasma production at high pressures”, *Jpn. J. Appl. Phys.* vol. 55, pp. 06HA02-1-06HA02-6, June, 2016. (SCI,EI)

5.

K.-C. Chen, K.-F. Chiu, K. Ogiwara, L.-W. Su, K. Uchino, and Y. Kawai, “Study of spatial profiles of capacitively coupled VHF H₂ plasma by simulation”, *Jpn. J. Appl. Phys.* vol. 56, pp. 01AC05-1-

01AC05-8, January, 2017. (SCI, EI)

Conference Papers :

1.

K.-C. Chen, K.-F. Chiu, K. Ogiwara, L.-W. Su, K. Uchino, and Y. Kawai, "Two-dimensional simulations of a VHF H₂ plasma for different discharge gaps", 68th Gaseous Electronics Conference (GEC)/9th International Conference on Reactive Plasmas (ICRP), October, 2015, vol. 60, pp. 82 (LW1 00027), American Society Applied Physics. Hawaii, U.S.A.

2.

K.-C. Chen, C.-F. Chen, C.-Y. Lien, K.-F. Chiu, J.-B. Shi, Y.-J. Tsai, T.-K. Lien, K. Ogiwara, K. Uchino, and Y. Kawai, "Mechanism of a VHF H₂ plasma production at high pressures", 37th International Symposium on Dry Process (DPS), November, 2015, pp. 113-114 (p-26), Japan Society Applied Physics. Awaji Island, Japan.

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